

Supplementary information

Facile Synthesis of Nitrogen-Doped Carbon Materials with Hierarchical Porous Structures for High-Performance Supercapacitors in Both Acid and Alkaline Electrolyte

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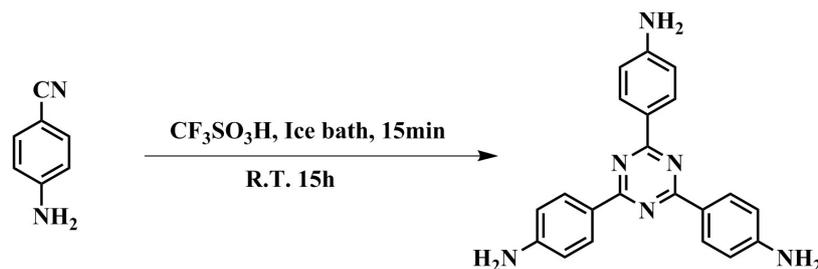
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1. Characterization

¹H magnetic resonance (NMR) spectrum of the 2,4,6-Tris(4-aminophenyl)-1,3,5-triazine (TAA) was carried out on a Bruker Advanced II AV500 MHz NMR spectrometer. Fourier transform infrared spectroscopy (FT-IR) spectra was measured from a Nicolet Avatar 360. Scanning electron microscopy (SEM) images were taken using a Su-70 instrument. The X-ray photoelectron spectroscopy (XPS) spectra were tested on a PHI Quantum-2000 photoelectron spectrometer (Al K α with 1486.6 eV). Electrochemical impedance spectroscopies (EIS) were carried out with the frequency of 10⁻² to 10⁵ Hz and at an amplitude of 5 mV.

2. Synthesis

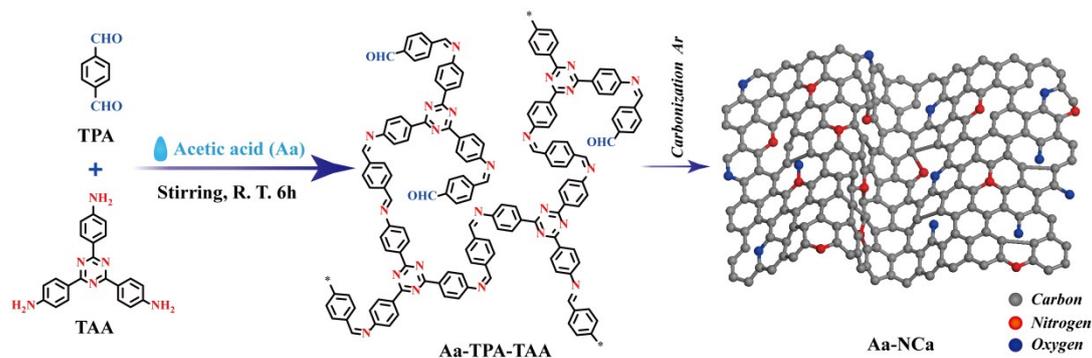
Synthesis of TAA



The synthesis of 2,4,6-tris(4-aminophenyl)-1,3,5-triazine (**TAA**) was performed according to previous literature procedure with a minor modification.³³ The detailed synthetic procedure and corresponding NMR are listed as follows:

0.708 g of 4-aminobenzonitrile (6 mmol) was added to 1 mL of trifluoromethane sulfonic acid in 10 mL round-bottom flask and stirred for 15 min at 0 °C by ice-bath. Then, the above mixed solution was further stirred for 15 h at room temperature. Subsequently, $\text{NH}_3 \cdot \text{H}_2\text{O}$ was added dropwise to the above solution to adjust pH value to 7. Finally, the resulting mixture was centrifuged for 3 times with large amount of deionized water and a yellow solid was obtained. [NMR] ^1H NMR (DMSO-d_6 , 500 MHz) $\delta = 5.91$ (s, 6H), 6.68 (d, 6H), 8.34 (d, 6H).

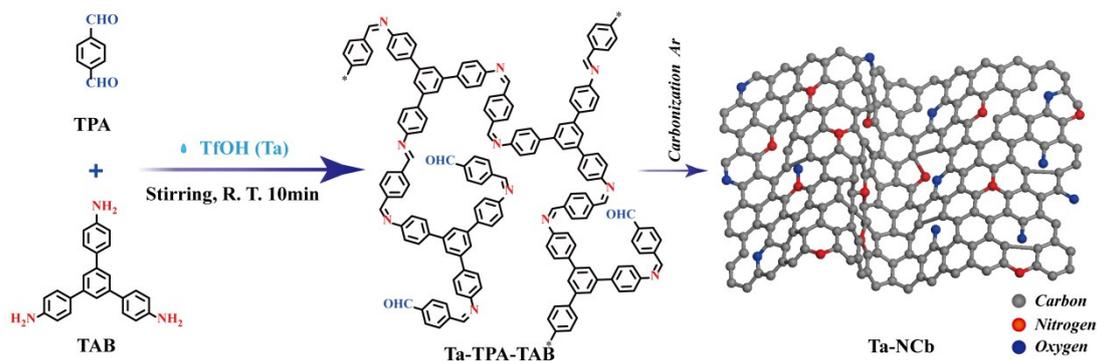
Synthesis of Aa-NCas



Scheme S1. Synthetic procedure of Aa-TPA-TAA and Aa-NCa by using acetic acid as catalyst.

Typically, 0.709 g of TAA (2 mmol) and 0.40 g of TPA (3 mmol) were taken in a 50 mL round bottom flask and dissolved in 10 mL of 1,3,5-trimethylbenzene, 1,4-dioxane mixed solvent ($v : v = 1 : 4$). To this solution, 1 mL of acetic acid (Aa) was added, and stirred at room temperature for 6 h. The reaction mixture was then centrifuged, washed with ethanol for 3 times to remove unreacted monomers, thus affording solid powder. After drying in vacuum, the as-prepared precursor (Aa-TPA-TAA) was carbonized at 850 °C for 2 h with a heating rate of 5 °C min^{-1} under Ar atmosphere to prepare Aa-NCa₈₅₀.

Synthesis of Ta-NCBs



Scheme S2. Synthetic procedure of Ta-TPA-TAB and Ta-NCb by using TfOH as catalyst.

Typically, 0.702 g of 1,3,5-tris(4-aminophenyl)benzene (TAB) (2 mmol) and 0.40 g of TPA (3 mmol) were taken in a 50 mL round bottom flask and dissolved in 10 mL of 1,3,5-trimethylbenzene, 1,4-dioxane mixed solvent ($v : v = 1 : 4$). To this solution, 20 μL of trifluoromethanesulfonic acid was added, and precipitate was generated immediately. The reaction mixture was further stirred at room temperature for 10 min and then centrifuged, washed with ethanol for 3 times to remove unreacted monomers and afford solid powder. After drying in vacuum, the as-prepared precursor Ta-TPA-TAB was carbonized at 850 $^{\circ}\text{C}$ for 2 h with a heating rate of 5 $^{\circ}\text{C min}^{-1}$ under Ar atmosphere to prepare Ta-NCb₈₅₀.

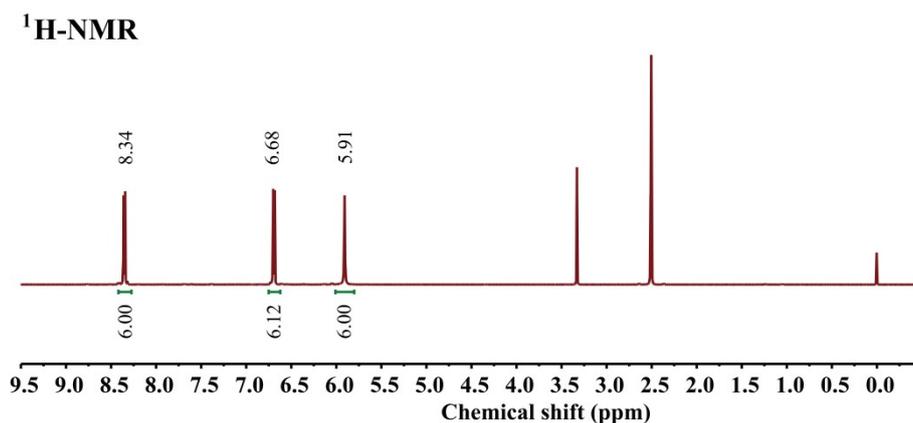


Fig. S1 ¹H spectrum of the TAA.

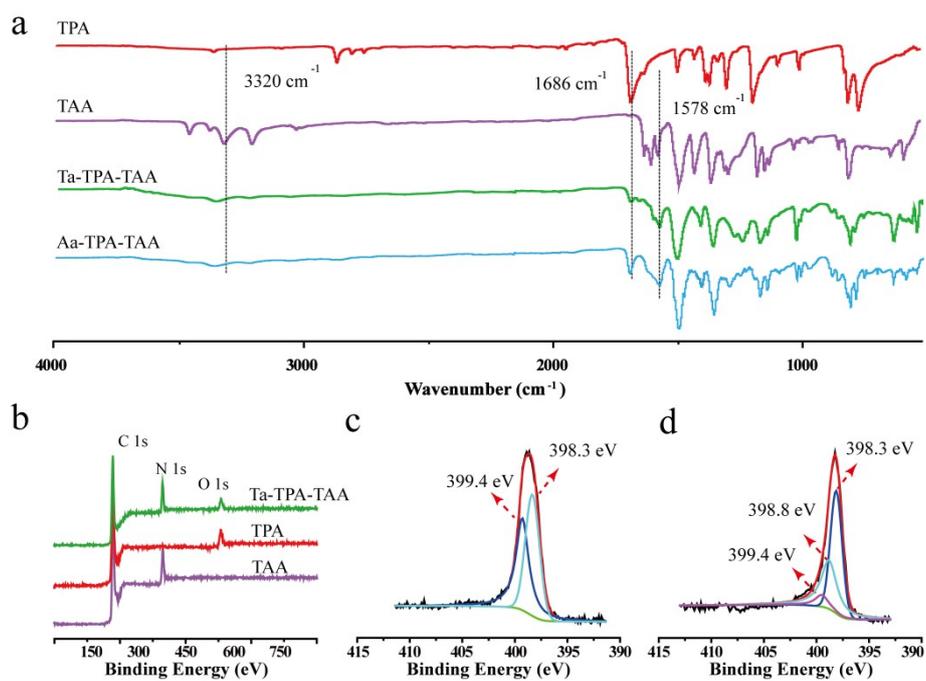


Fig. S2 FT-IR spectra of TPA, TAA, Ta-TPA-TAA and Aa-TPA-TAA (a); XPS survey spectra of TPA, TAA and Ta-TPA-TAA (b); High-resolution N 1s XPS spectra of TAA (c) and Ta-TPA-TAA (d).

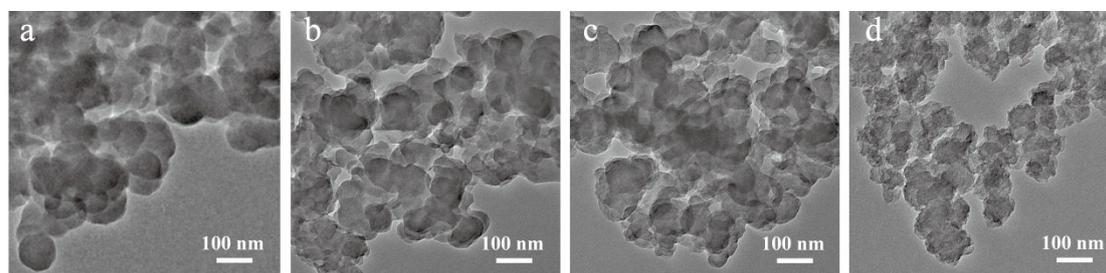


Fig. S3 TEM images of precursor Ta-TPA-TAA (a), Ta-NCa₆₅₀ (b), Ta-NCa₇₅₀ (c) and Ta-NCa₉₅₀ (d).

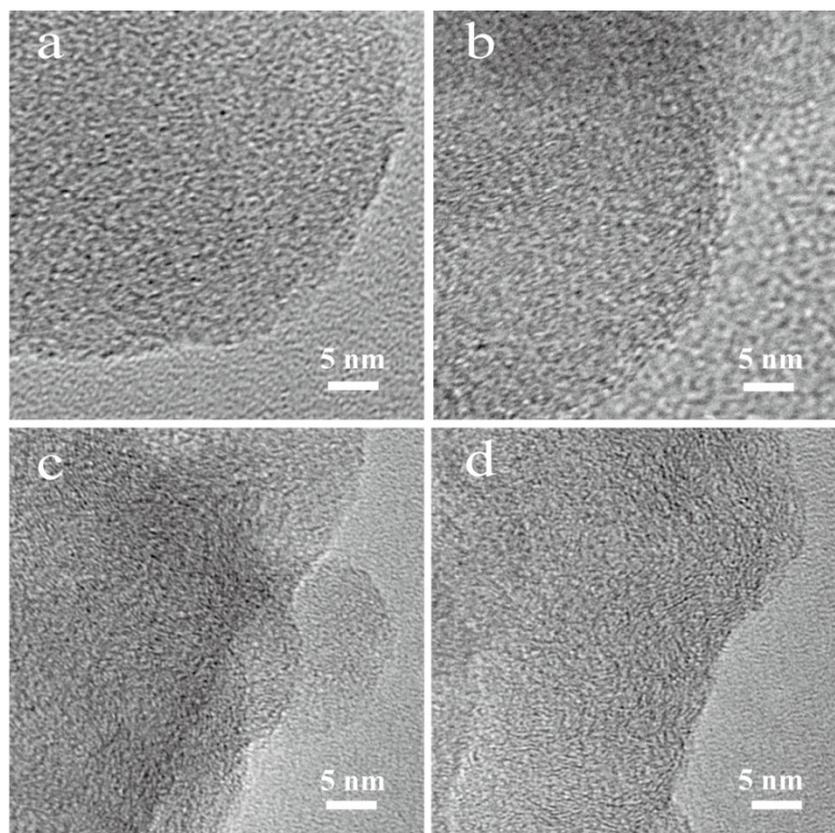


Fig. S4 High resolution TEM images of Ta-NCa₆₅₀ (a), Ta-NCa₇₅₀ (b), Ta-NCa₈₅₀ (c), Ta-NCa₉₅₀ (d).

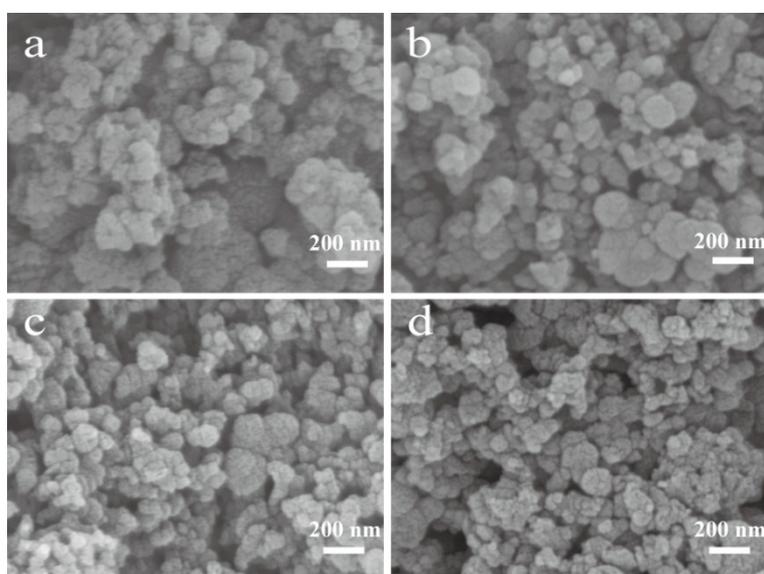


Fig. S5 SEM images of Ta-NCa₆₅₀ (a), Ta-NCa₇₅₀ (b), Ta-NCa₈₅₀ (c) and Ta-NCa₉₅₀ (d).

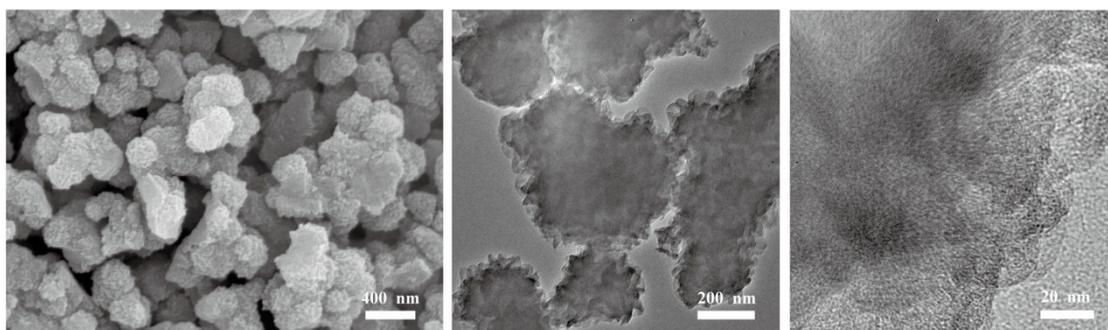


Fig. S6 SEM image of Aa-NCa₈₅₀ (a), TEM image of Aa-NCa₈₅₀ (b), high resolution TEM image of Aa-NCa₈₅₀ (c).

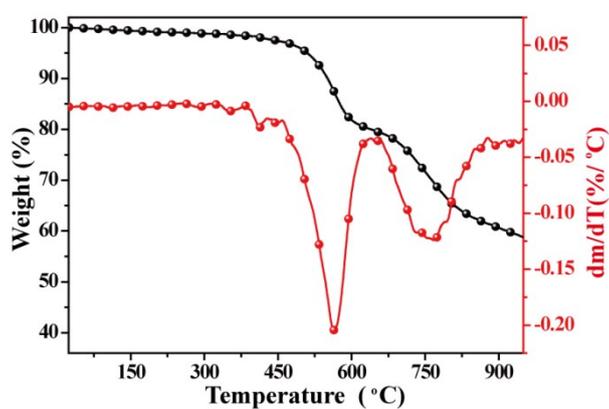


Fig. S7 TGA and DTA curves of precursor Ta-TPA-TAA.

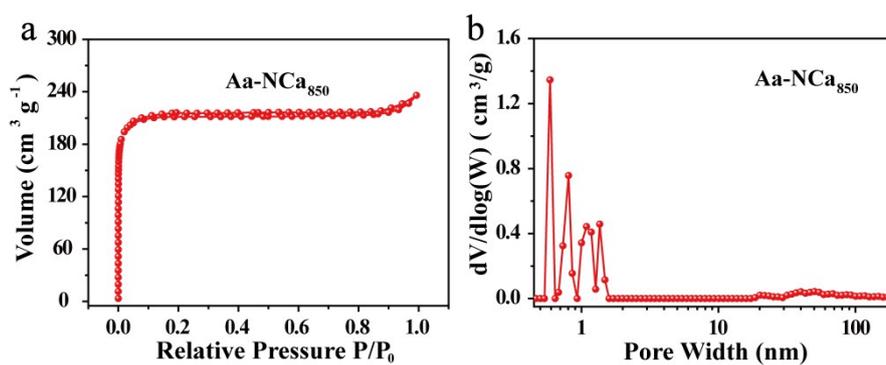


Fig. S8 N₂ adsorption/desorption isotherm (a) and the DFT pore size distribution (b) of Aa-NCa₈₅₀.

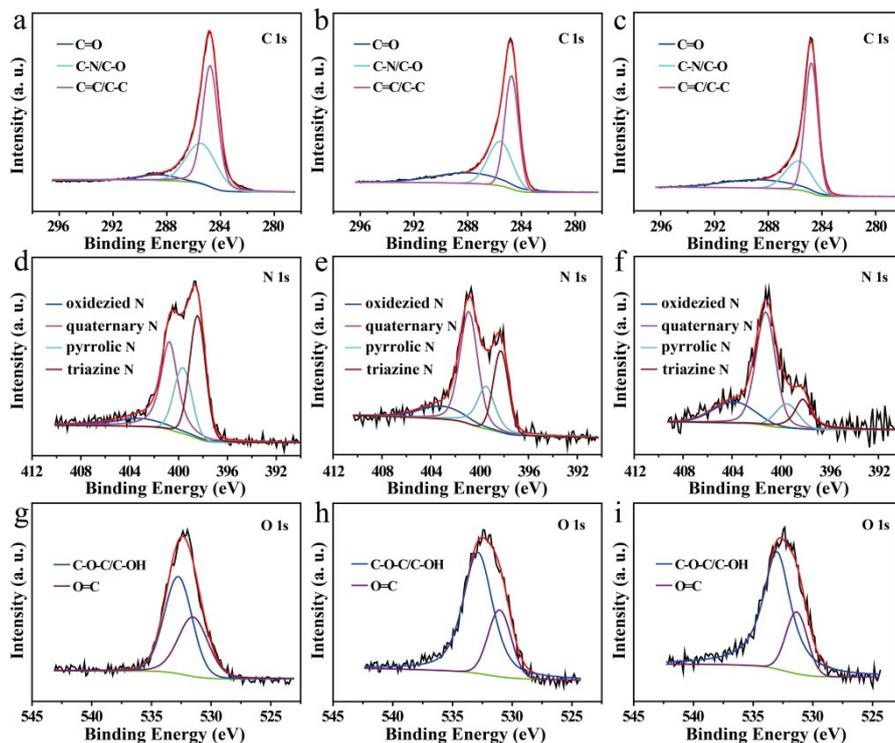


Fig. S9 High-resolution XPS spectra. Ta-NCa₆₅₀: of C 1s (a), N 1s (d) and O 1s (g) ; Ta-NCa₇₅₀: C 1s (b), N 1s (e) and O 1s (h); Ta-NCa₉₅₀: C 1s (c), N 1s (f) and O 1s (i).

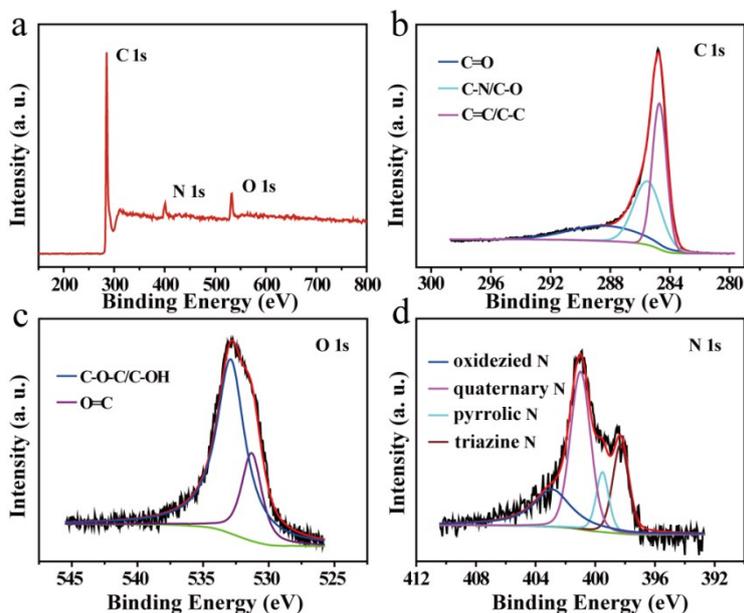


Fig. 10 XPS survey spectrum of Aa-NCa₈₅₀ (a); High-resolution XPS spectra of C 1s (b), O 1s (c) and N 1s (d) for Aa-NCa₈₅₀.

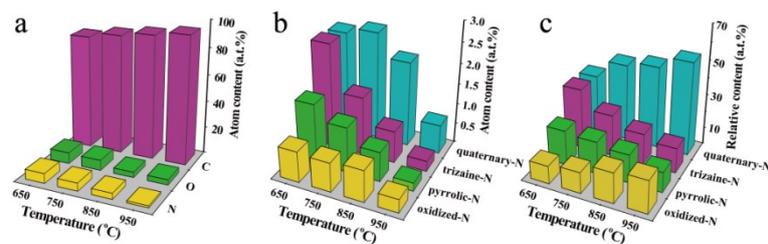


Fig. S11 Carbon, nitrogen and oxygen contents of Ta-NiCa₆₅₀, Ta-NiCa₇₅₀, Ta-NiCa₈₅₀ and Ta-NiCa₉₅₀ (a); The absolute content variations of oxidized N, graphitic N, pyrrolic N, and triazine N in Ta-NiCa₆₅₀, Ta-NiCa₇₅₀, Ta-NiCa₈₅₀ and Ta-NiCa₉₅₀ (b); The relative content variations of oxidized N, graphitic N, pyrrolic N, and triazine N in Ta-NiCa₆₅₀, Ta-NiCa₇₅₀, Ta-NiCa₈₅₀ and Ta-NiCa₉₅₀ (c).

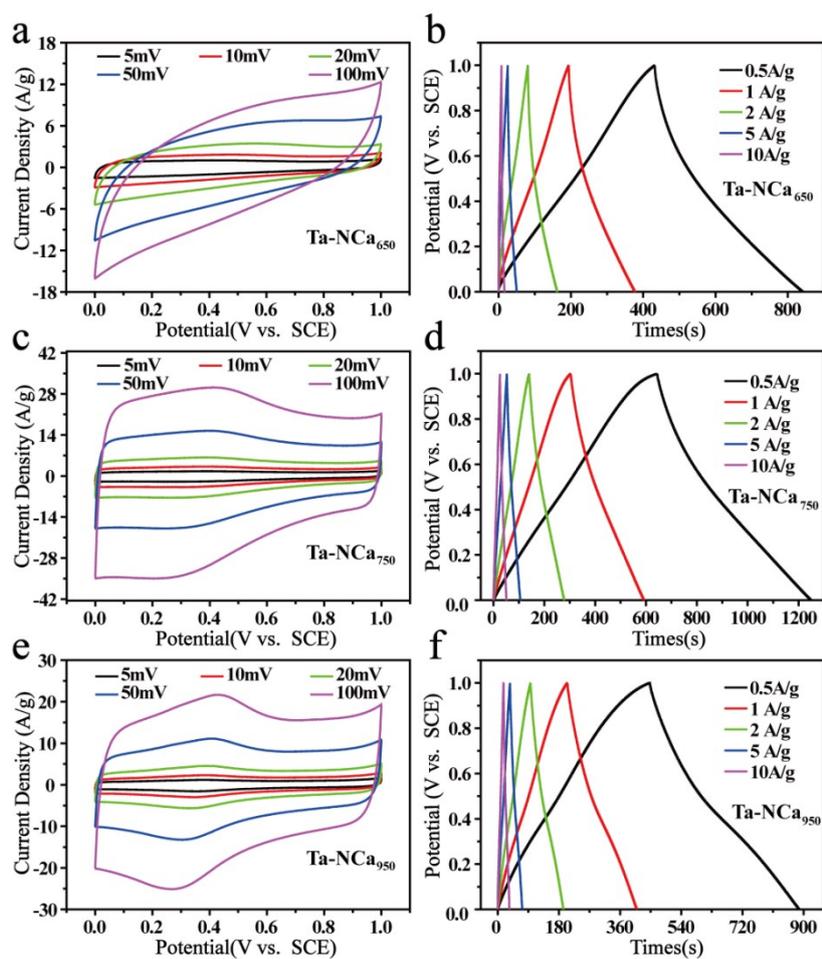


Fig. S12 Electrochemical performances of Ta-NiCa₆₅₀, Ta-NiCa₇₅₀ and Ta-NiCa₉₅₀ in 1 M H₂SO₄. CV curves of Ta-NiCa₆₅₀, Ta-NiCa₇₅₀ and Ta-NiCa₉₅₀ (e) at the scan rates from 5 to 100 mV s⁻¹; Galvanostatic charge discharge profiles of Ta-NiCa₆₅₀, Ta-NiCa₇₅₀ and Ta-NiCa₉₅₀ (f) at the current densities from 0.5 to 10 A g⁻¹.

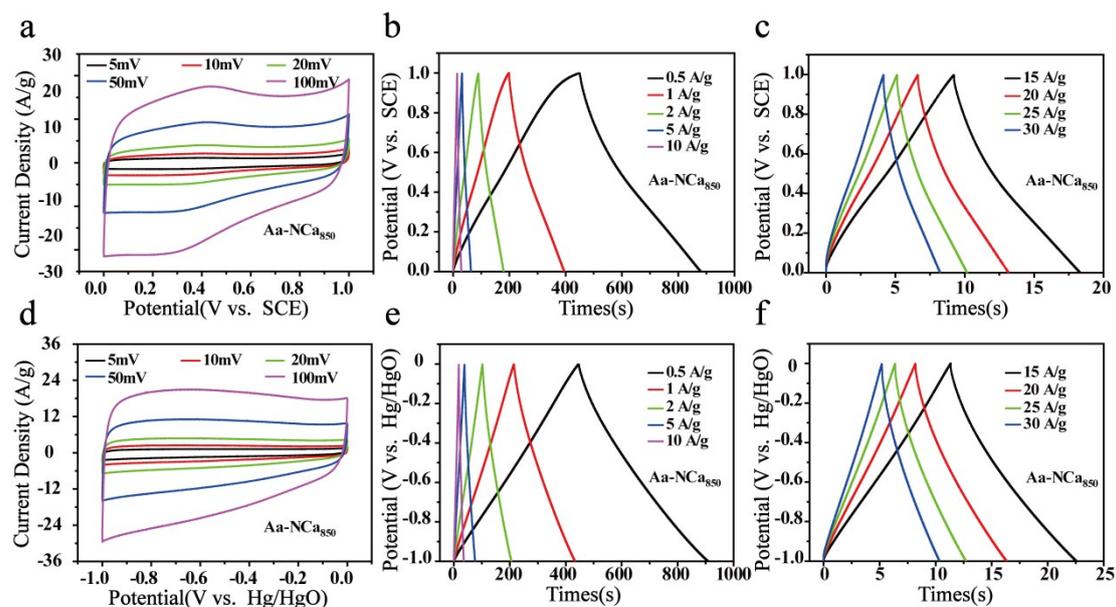


Fig. 13 CV curves of Aa-NCa₈₅₀ at the scan rates from 5 to 100 mV s⁻¹ in 1 M H₂SO₄ (a); Galvanostatic charge discharge profiles of Aa-NCa₈₅₀ at the current densities from 0.5 to 30 A g⁻¹ in 1 M H₂SO₄ (b and c); CV curves of Aa-NCa₈₅₀ at the scan rates from 5 to 100 mV s⁻¹ in 6 M KOH (d); Galvanostatic charge discharge profiles of Aa-NCa₈₅₀ at the current densities from 0.5 to 30 A g⁻¹ in 6 M KOH (e and f).

CV curves of Aa-NCa₈₅₀ display a quasi-rectangular shape and the CV curves keep almost unchanged with the increase of the scan rates from 5 to 100 mV s⁻¹. At a high current of 30 A g⁻¹, Ta-NCas have specific capacitances of 123 F g⁻¹ in H₂SO₄ and 156 F g⁻¹ in KOH.

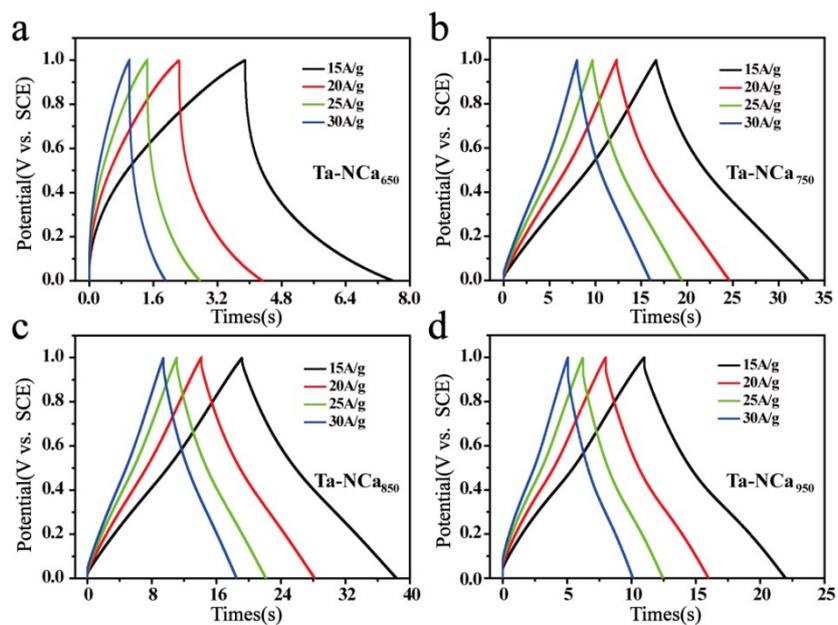


Fig. S14 Galvanostatic charge discharge profiles of Ta-NCa₆₅₀ (a), Ta-NCa₇₅₀ (b), Ta-NCa₈₅₀ (c) and Ta-NCa₉₅₀ (d) at the current densities from 15 to 30 A g⁻¹ in 1 M H₂SO₄.

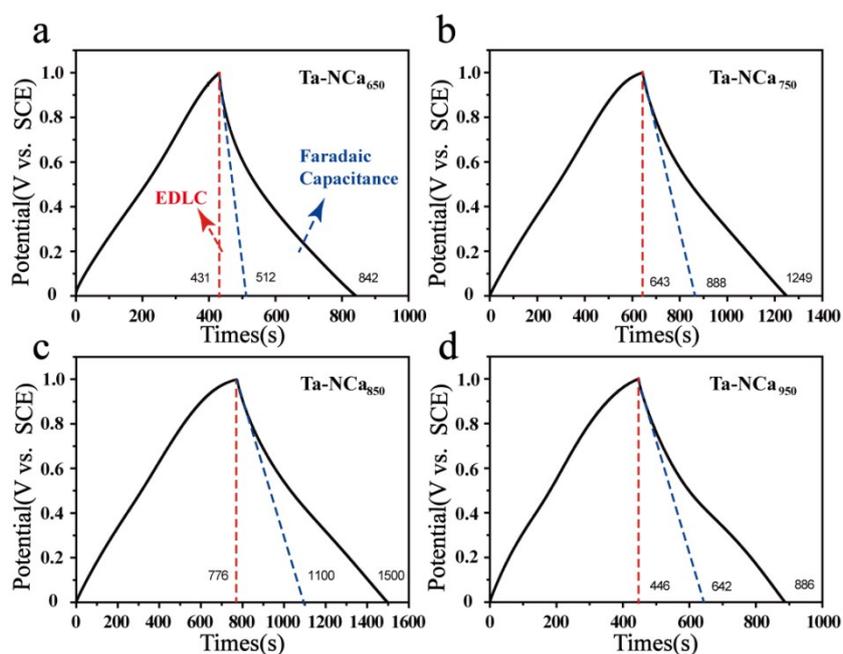


Fig. S15 Galvanostatic charge discharge profiles of Ta-NCa₆₅₀ (a), Ta-NCa₇₅₀ (b), Ta-NCa₈₅₀ (c) and Ta-NCa₉₅₀ (d) at 0.5 A g⁻¹ in 1 M H₂SO₄ with the estimated EDLC and faradaic capacitance contributions being obtained from the discharge portions of differing slope.

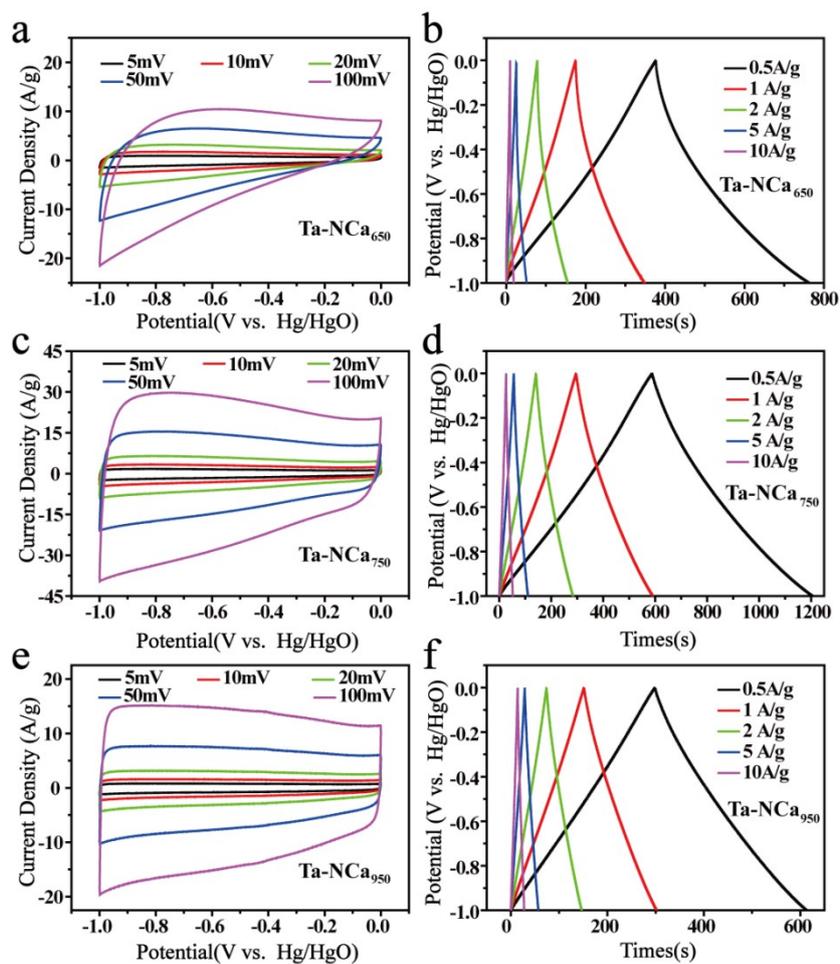


Fig. S16 Electrochemical performances of Ta-NCa₆₅₀, Ta-NCa₇₅₀ and Ta-NCa₉₅₀ in 6 M KOH. CV curves of Ta-NCa₆₅₀ (a), Ta-NCa₇₅₀ (c) and Ta-NCa₉₅₀ (e) at the scan rates from 5 to 100 mV s⁻¹; Galvanostatic charge discharge profiles of Ta-NCa₆₅₀ (b), Ta-NCa₇₅₀ (d) and Ta-NCa₉₅₀ (f) at the current density from 0.5 to 10 A g⁻¹.

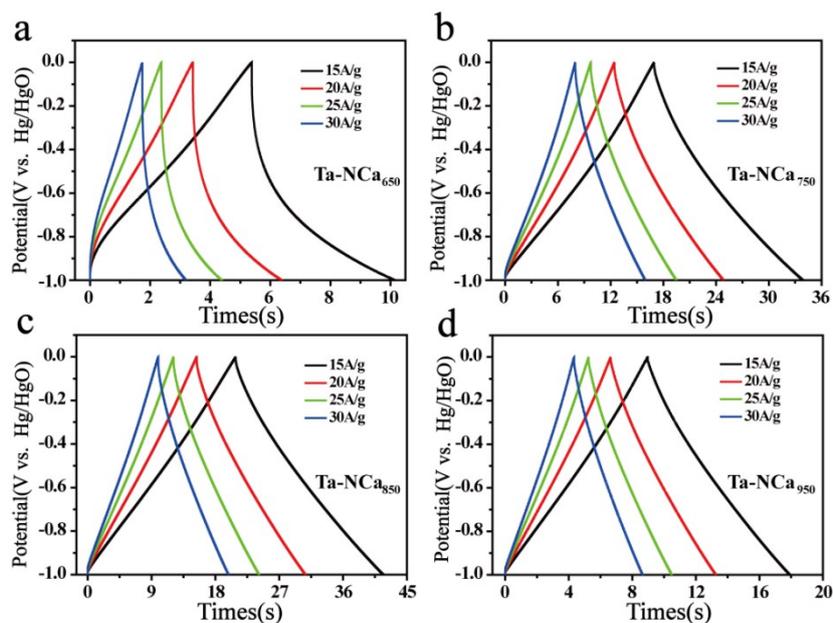


Fig. S17 Galvanostatic charge discharge profiles of Ta-NiCa₆₅₀ (a), Ta-NiCa₇₅₀ (b), Ta-NiCa₈₅₀ (c) and Ta-NiCa₉₅₀ (d) at the current densities from 15 to 30 A g⁻¹ in 6 M KOH.

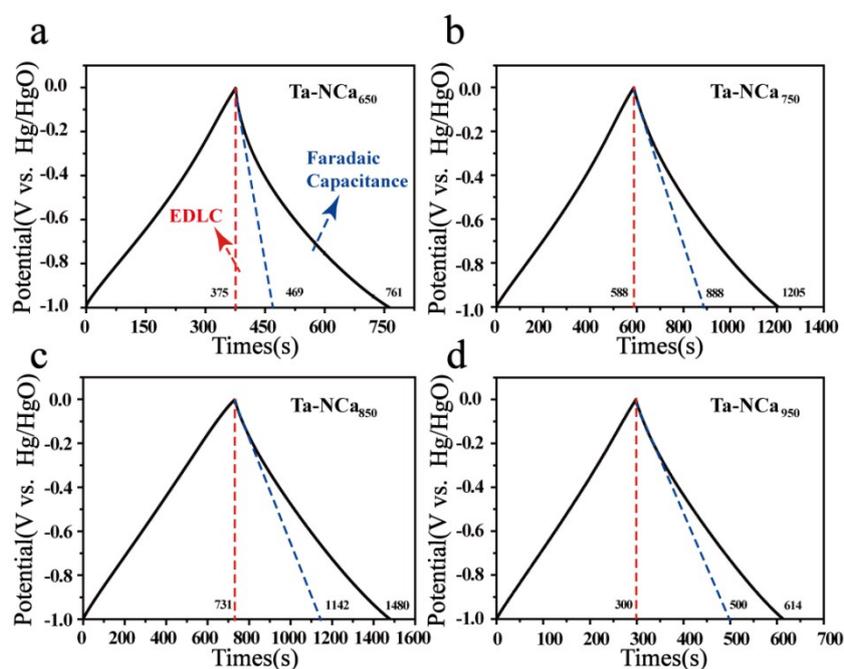


Fig. S18 Galvanostatic charge discharge profiles of Ta-NiCa₆₅₀ (a), Ta-NiCa₇₅₀ (b), Ta-NiCa₈₅₀ (c) and Ta-NiCa₉₅₀ (d) at 0.5 A g⁻¹ in 6 M KOH with the estimated EDLC and faradaic capacitance contributions being obtained from the discharge portions of differing slope.

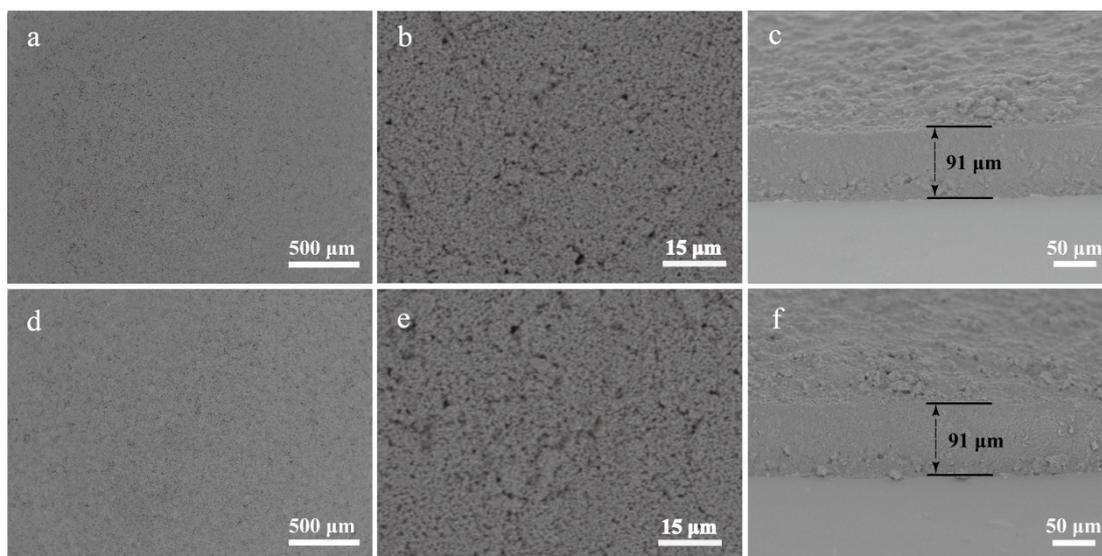


Fig. S19 SEM images of the working electrode film: surface (a, b) and cross section (c) before 5000 cycles, surface (d, e) and cross section (f) after 5000 cycles.

The thickness of the working electrode film is about 91 μm . No obvious morphology or thickness change can be observed to the working electrode film after 5000 cycles.

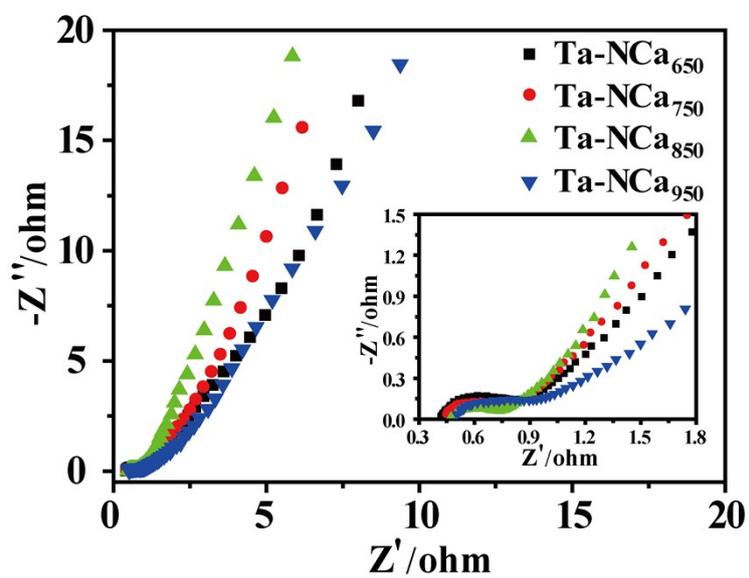


Fig. S20 Nyquist plots of Ta-NCAs, The inset is magnified higher frequency region.

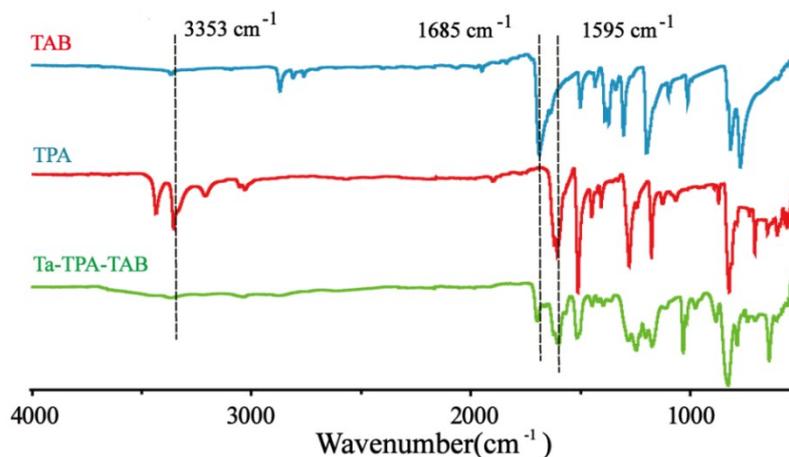


Fig. S21 FT-IR spectra of TPA, TAB, Ta-TPA-TAB.

In the FT-IR spectrum of Ta-TPA-TAB, characteristic peak at $\sim 3320\text{ cm}^{-1}$ derived from N-H as well as the peak at 1686 cm^{-1} derived from C=O attenuates greatly, while absorption peak at 1578 cm^{-1} (C=N) appears, providing strong evidence for the successful synthesis of Schiff-base polymer Ta-TPA-TAB.

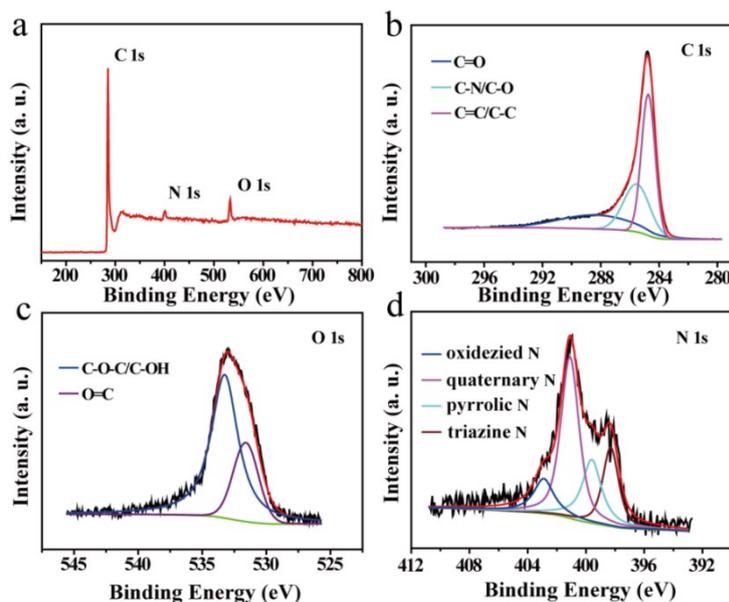


Fig. S22 XPS survey spectrum of Ta-NCb₈₅₀ (a); high-resolution XPS spectra of C 1s (b), O 1s (c) and N 1s (d) for Ta-NCb₈₅₀.

The XPS spectra of Ta-NCb₈₅₀ is similar to that of Ta-NCa₈₅₀ (Figure 3a-d) and corresponding analysis is described in the main text.

Table S1 surface elemental composition (atomic %) of TAA, TPA and Ta-TPA-TAA.

Samples	Composition (a.t. %)		
	C	N	O
TAA	75.35	24.65	0
TPA	74.97	0	25.03
Ta-TPA-TAA	76.50	14.32	9.18

Table S2 Surface area, porosity, surface elemental composition (atomic %) of samples.

	$S_{\text{BET}}^{\text{a}}$	$S_{\text{micro}}^{\text{b}}$	$V_{\text{total}}^{\text{c}}$	Composition (a.t. %) ^d		
	$\text{m}^2 \text{g}^{-1}$	$\text{m}^2 \text{g}^{-1}$	$\text{cm}^3 \text{g}^{-1}$	C	N	O
Ta-NCa ₆₅₀	373	332	0.24	84.50	7.26	8.24
Ta-NCa ₇₅₀	440	414	0.29	88.45	5.90	7.64
Ta-NCa ₈₅₀	706	654	0.44	91.59	4.39	4.02
Ta-NCa ₉₅₀	950	802	0.54	94.67	1.51	3.82
Aa-NCa ₈₅₀	722	715	0.40	91.07	3.85	5.08
Ta-NCb ₈₅₀	896	775	0.51	90.9	3.74	5.36

^a Specific surface area obtained from BET. ^b Surface area of micropores calculated by the t-plot method. ^c Total pore volume. ^d Atomic percent of elements obtained from XPS analysis.

Table S3 Heteroatoms doped carbons as electrode materials of supercapacitors.

Electrode Materials	Electrolyte	Capacitance (F g ⁻¹)	Current Density	Ref.
Ta-NCa ₈₅₀	6 M KOH	374.5	0.5 A g ⁻¹	This work
	1 M H ₂ SO ₄	362	0.5 A g ⁻¹	
TCNQ-CTF-800	1 M KOH	383	0.2 A g ⁻¹	5
PMC-650	1 M H ₂ SO ₄	312	0.5 A g ⁻¹	6
HFAC-2	1 M KOH	525	0.25 A g ⁻¹	7
	1 M H ₂ SO ₄	556	0.25 A g ⁻¹	
ABF-9%M	6 M KOH	289	0.5 A g ⁻¹	11
TNNs-550	1 M H ₂ SO ₄	298	0.2 A g ⁻¹	13
N-MCS-200	6 M KOH	292	1 A g ⁻¹	28
aNMC-0.5	1 M H ₂ SO ₄	328	0.5 A g ⁻¹	33
TC	6 M KOH	286.6	0.5 A g ⁻¹	34
N/S-HCS	6 M KOH	280	1 A g ⁻¹	35
G/CNTs-200	6 M KOH	202	0.5 A g ⁻¹	46